

FIG. 1

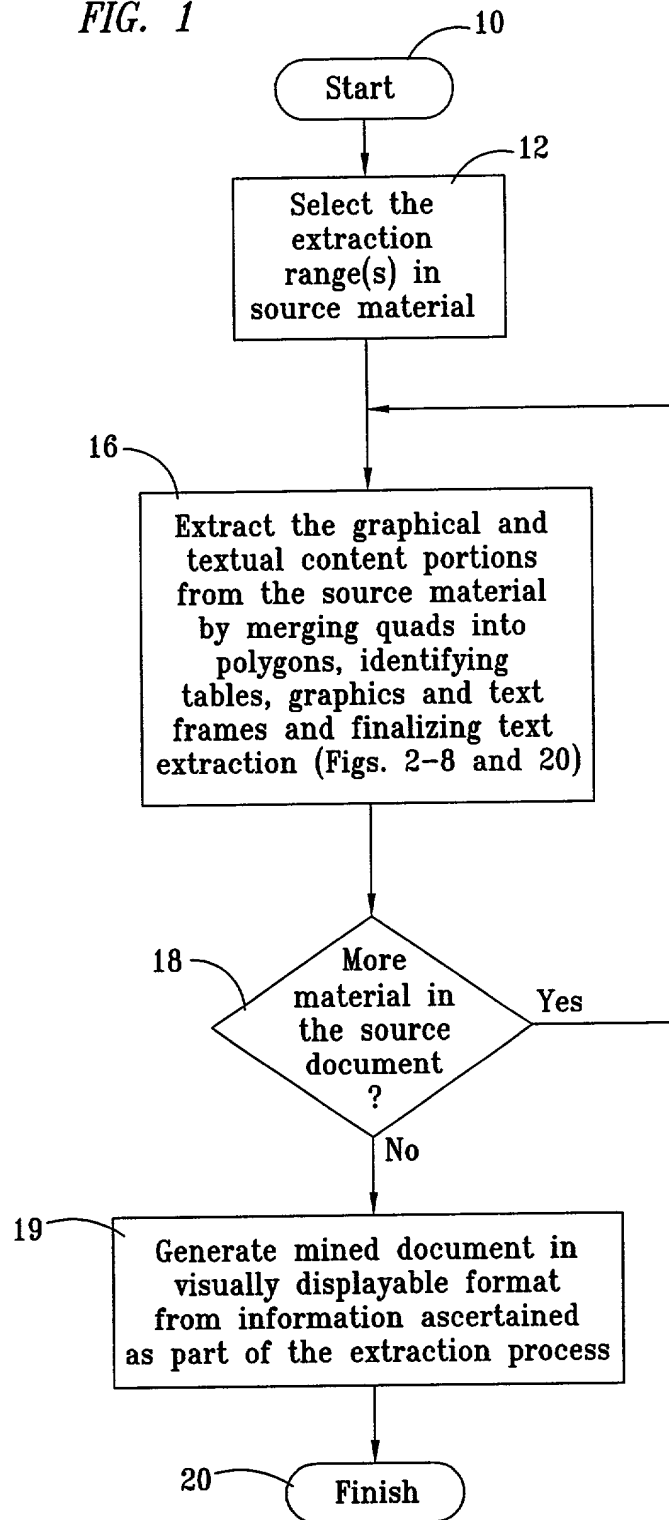


FIG. 2

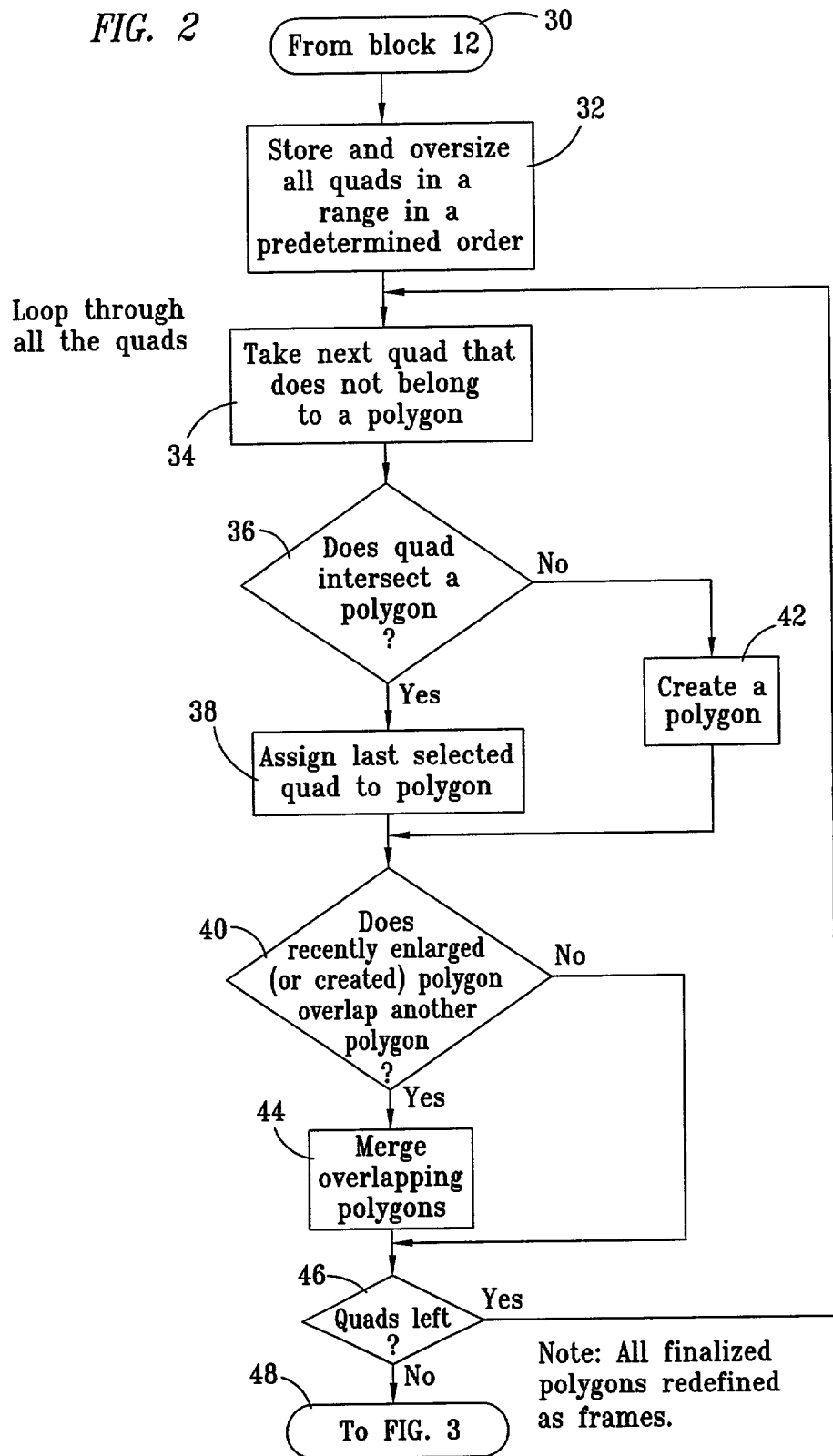


FIG. 3

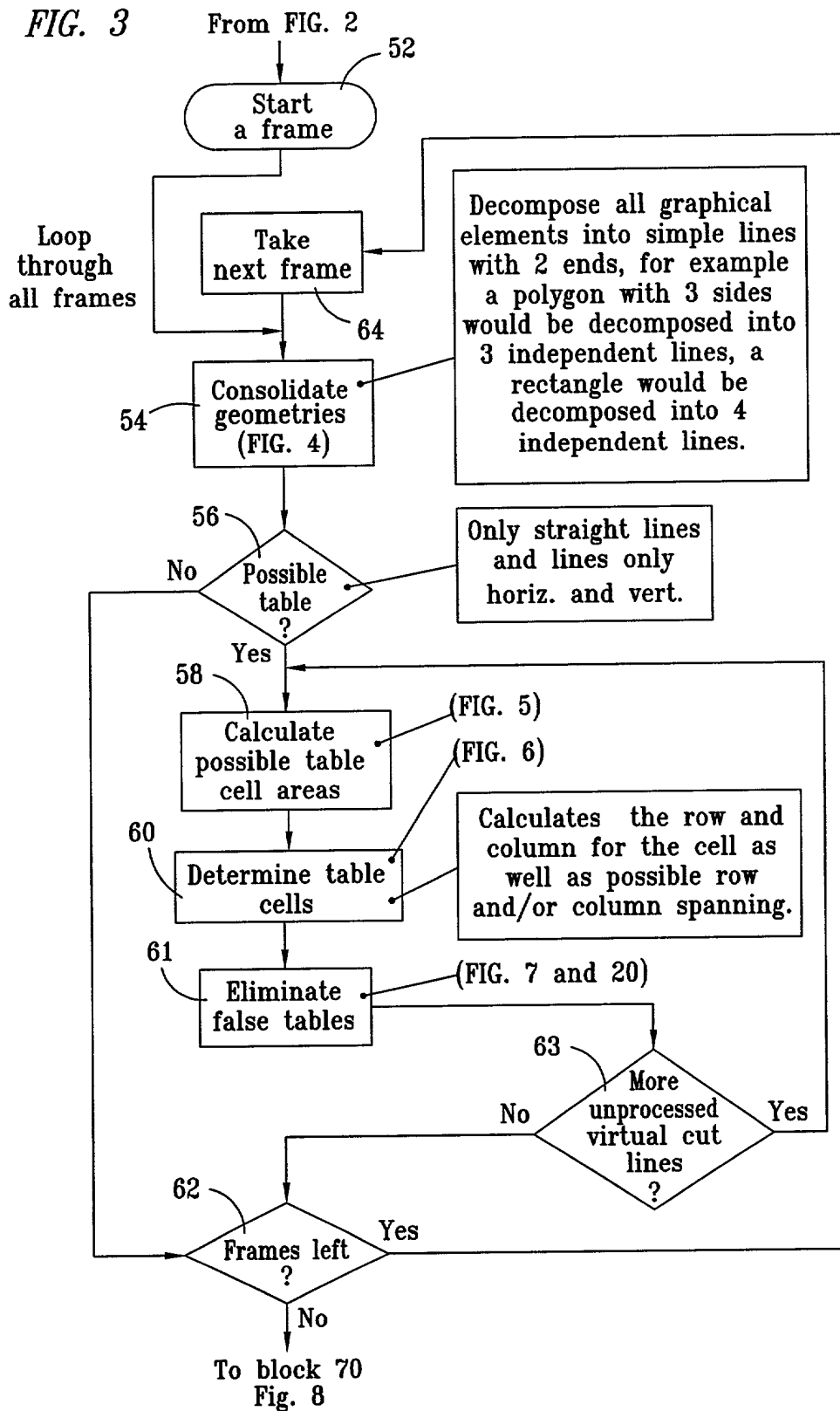


FIG. 4 From block
52 or 64

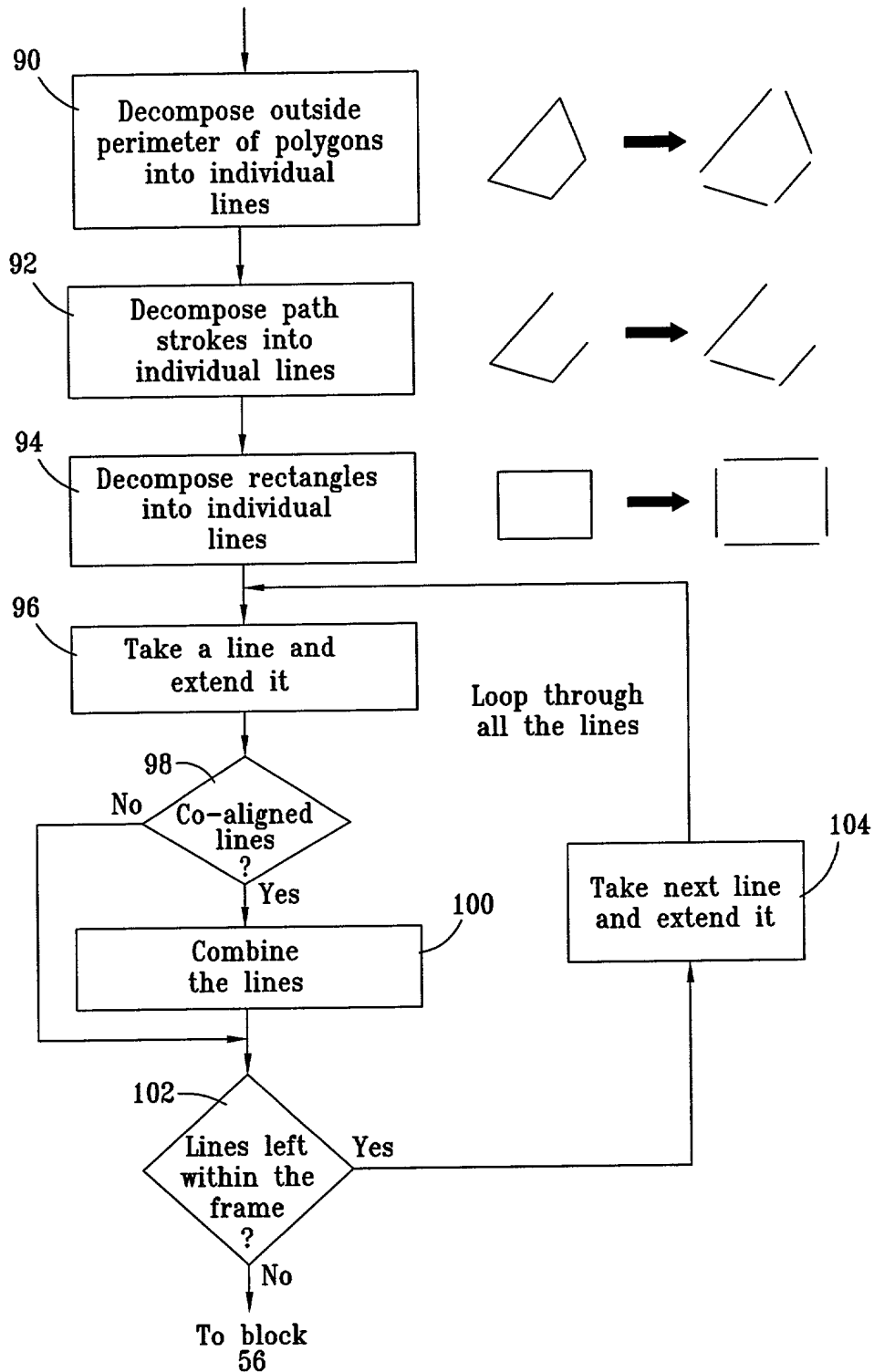


FIG. 5

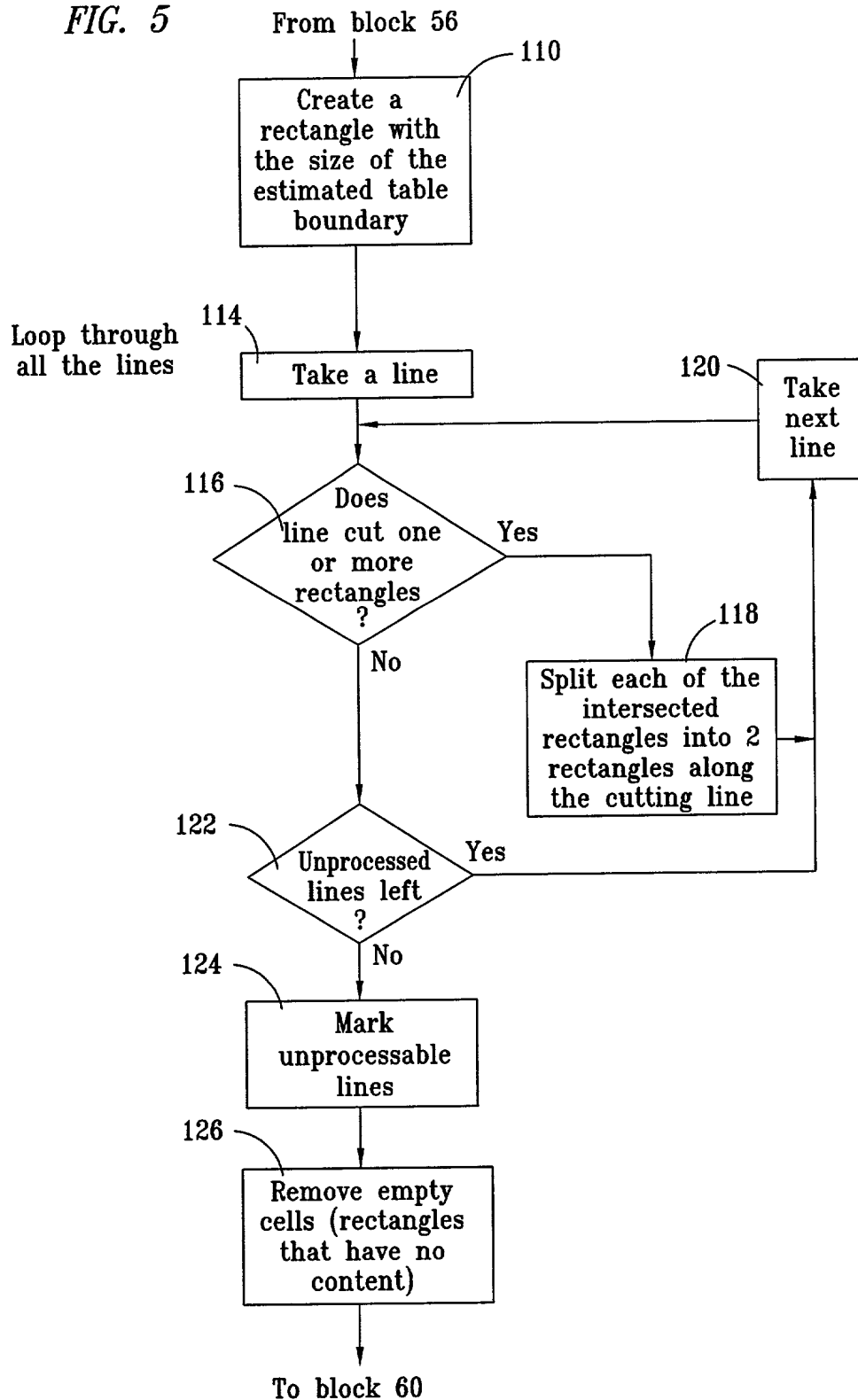


FIG. 6

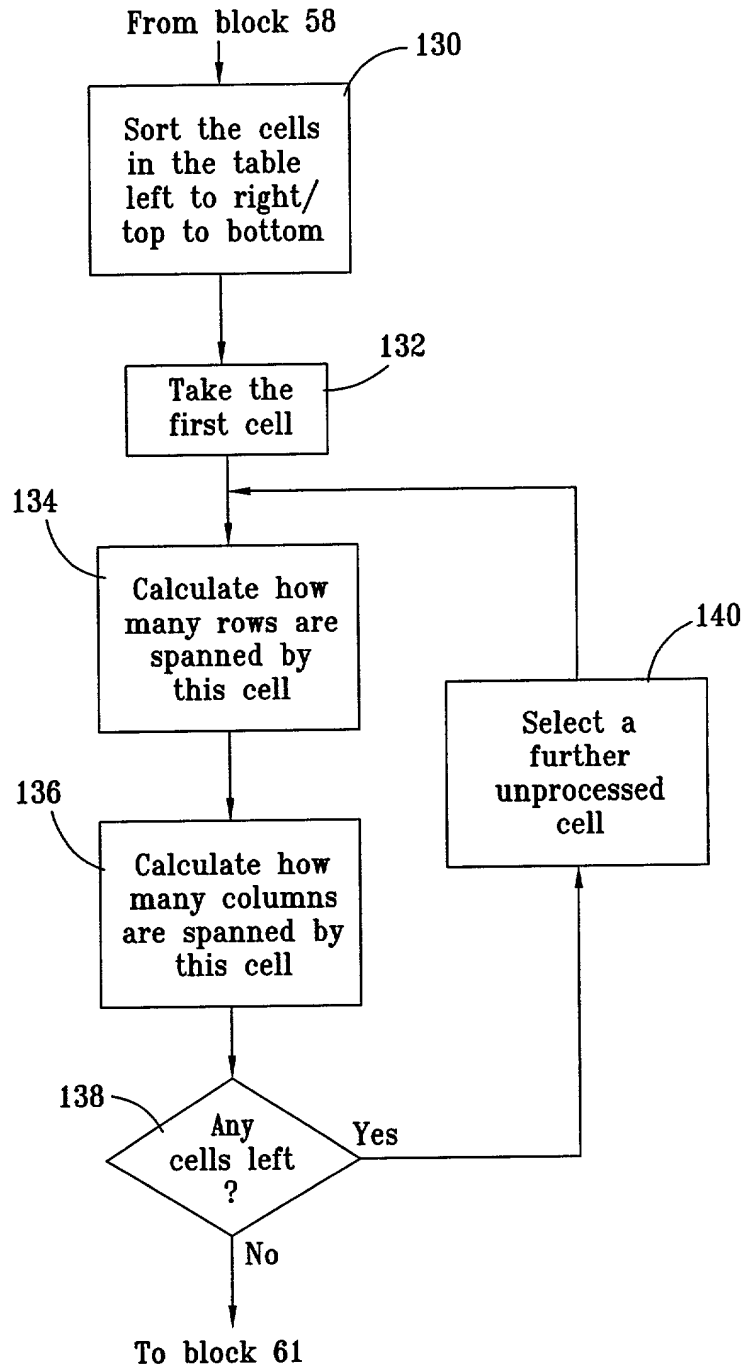


FIG. 7

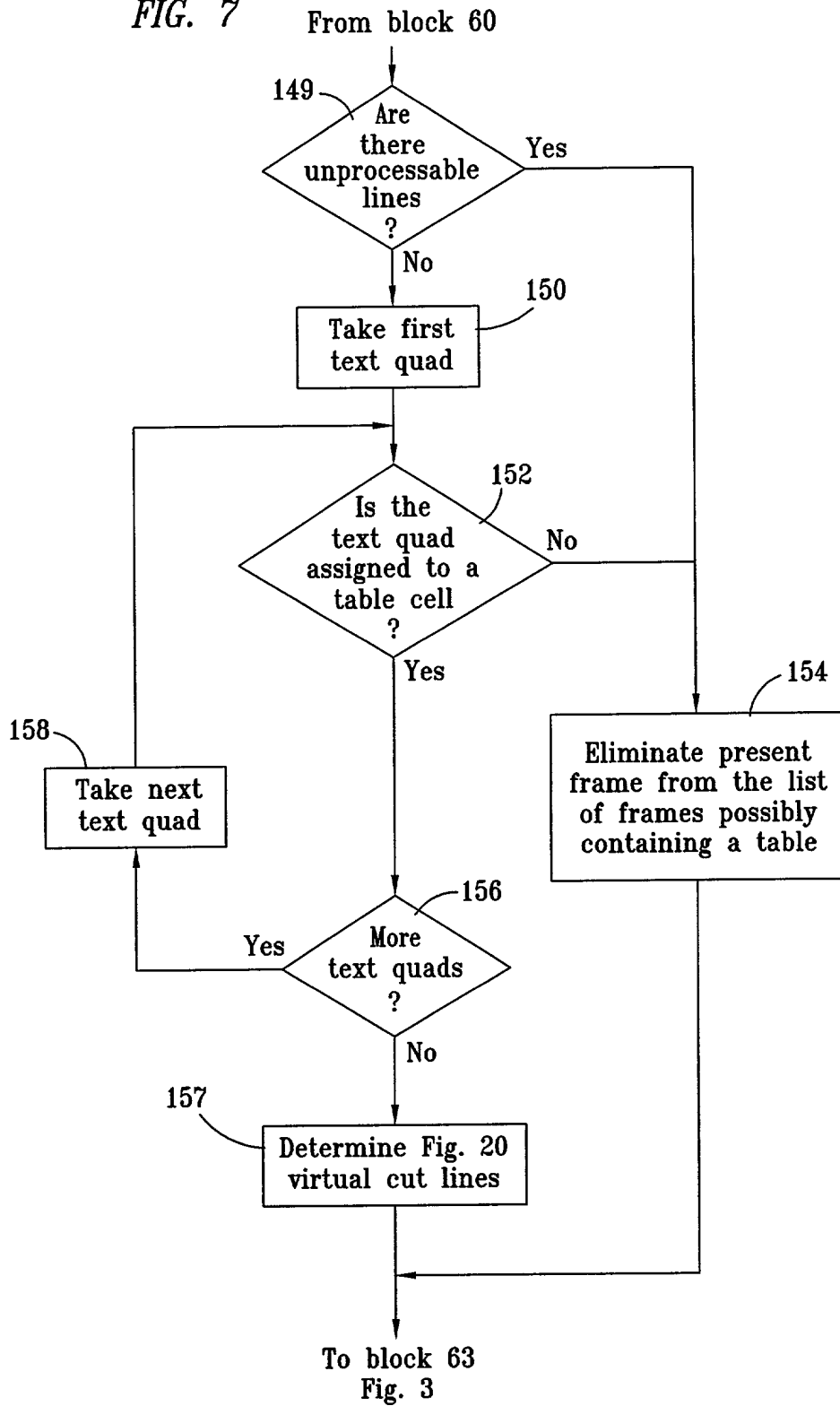


FIG. 8

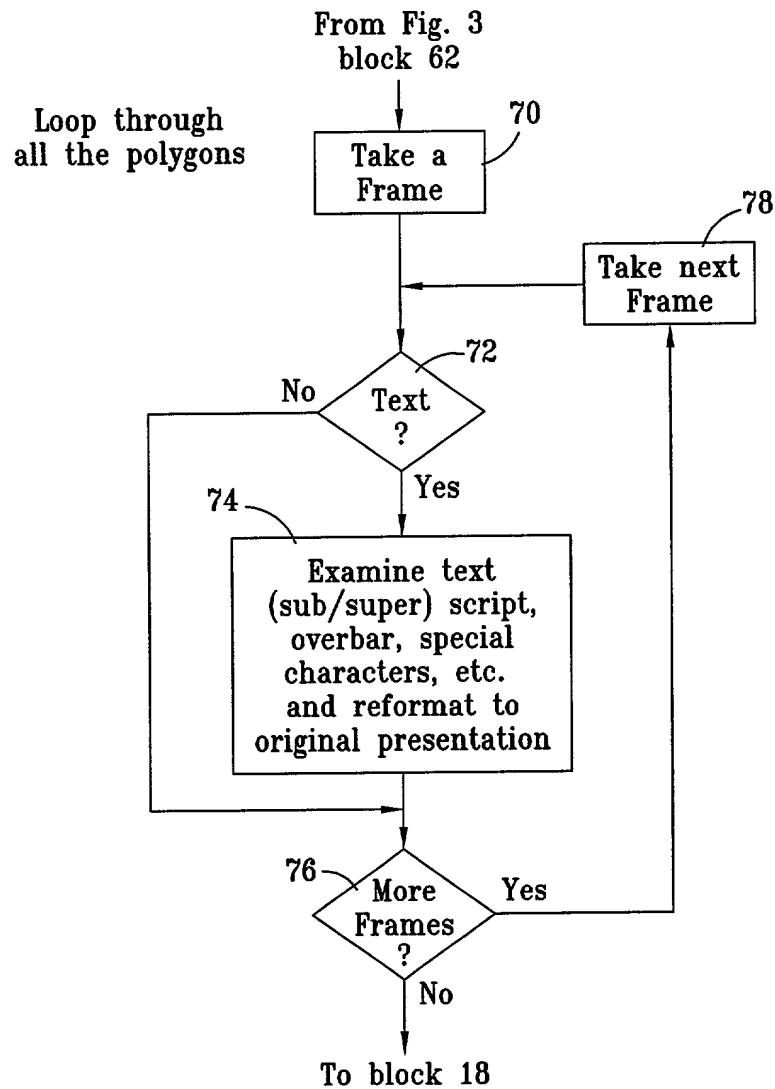


FIG. 9A

The diagram shows a central block labeled 160, "MICROPOWER INTEGRATED VOLTAGE REFERENCES". To its left is block 162, and to its right is block 164. Below block 160 is block 166, which lists applications: Portable Meter Reference, Portable Test Instruments, Battery Operated Systems, and Current-Loop Instrumentation. To the right of block 166 is block 170, which describes the LT1004 as a two-terminal band-gap reference diode. Below block 170 is block 172, which states the device is characterized for operation from -40°C to 85°C. To the right of block 172 is block 174, which shows a pinout diagram for a package with pins labeled CATHODE, NC, CATHODE, NC, CATHODE, NC, and CATHODE. To the right of block 174 is block 176, which shows a pinout diagram for a package with pins labeled ANODE and CATHODE. The entire diagram is enclosed in a dashed border with a label "A" in a circle at the bottom right.

160 MICROPOWER INTEGRATED VOLTAGE REFERENCES

162

164

166

Applications:

- Portable Meter Reference
- Portable Test Instruments
- Battery Operated Systems
- Current-Loop Instrumentation

170

The LT1004 micropower voltage reference is a two terminal band-gap reference diode designed to provide high accuracy and excellent temperature characteristics at very low operating currents. Optimizing the key parameters in the design, processing, and testing of the device results in specifications previously attainable only with selected units.

172

The LT1004 is characterized for operation from -40°C to 85°C .

174

CATHODE NC CATHODE NC CATHODE NC CATHODE

176

ANODE CATHODE

A

The LT1004 micropower voltage reference is a two terminal band-gap reference diode designed to provide high accuracy and excellent temperature characteristics at very low operating currents. Optimizing the key parameters in the design, processing, and testing of the device results in specifications previously attainable only with selected units.

The LT1004 is characterized for operation from 0°C to 70°C. The LT10041 is characterized for operation from -40°C to 85°C.

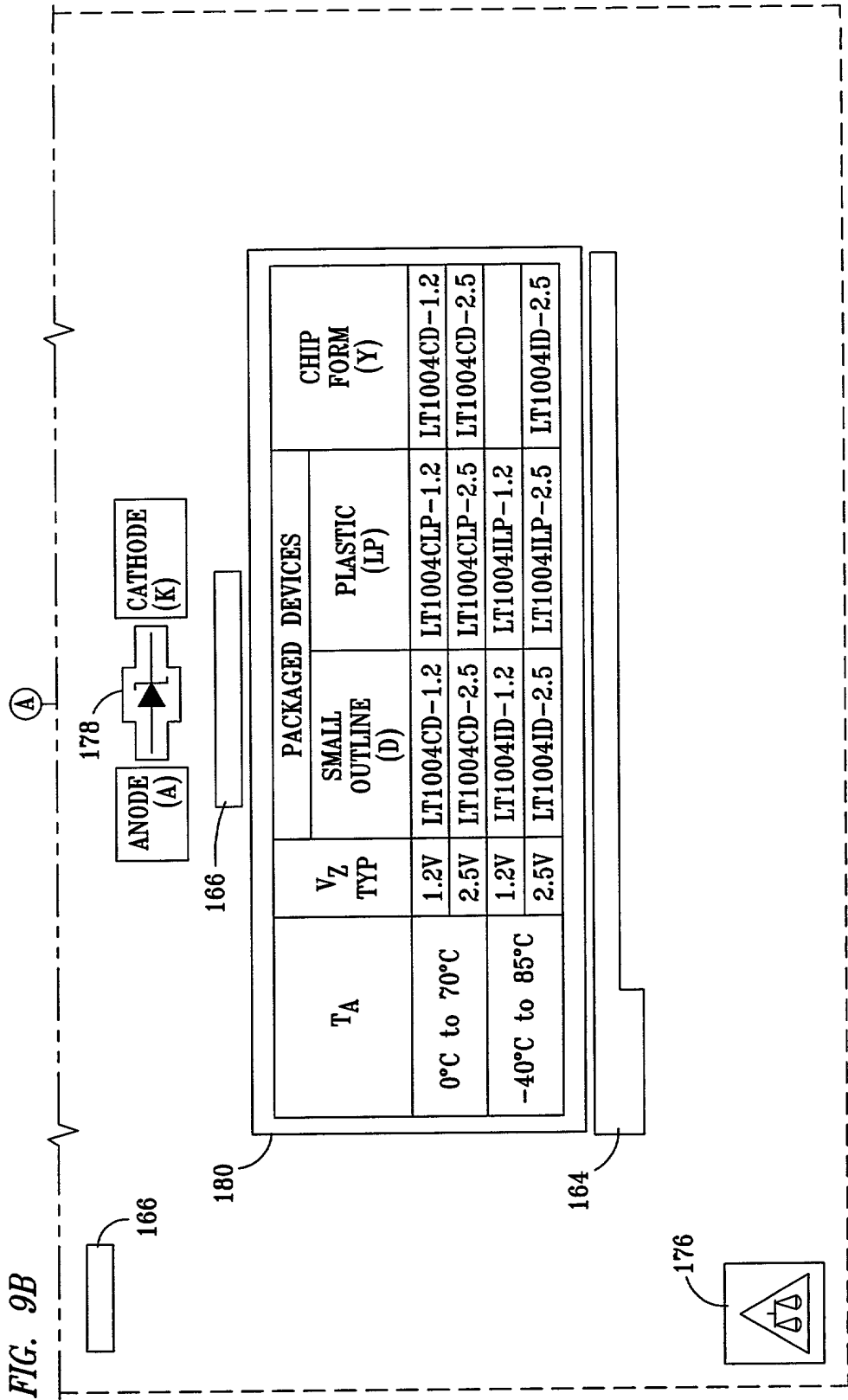


FIG. 10

T _A	V _Z TYP	PACKAGED DEVICES		CHIP FORM (Y)
		SMALL OUTLINE (D)	PLASTIC (LP)	
0°C to 70°C	1.2V	LT1004CD-1.2	LT1004CLP-1.2	LT1004CD-1.2
	2.5V	LT1004CD-2.5	LT1004CLP-2.5	LT1004CD-2.5
-40°C to 85°C	1.2V	LT1004ID-1.2	LT1004ILP-1.2	
	2.5V	LT1004ID-2.5	LT1004ILP-2.5	LT1004ID-2.5

FIG. 11

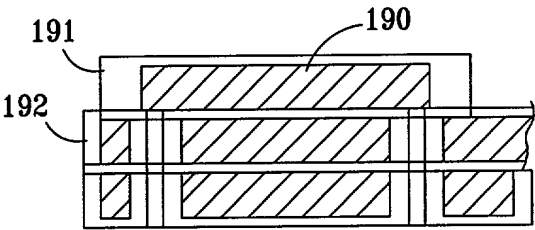


FIG. 12

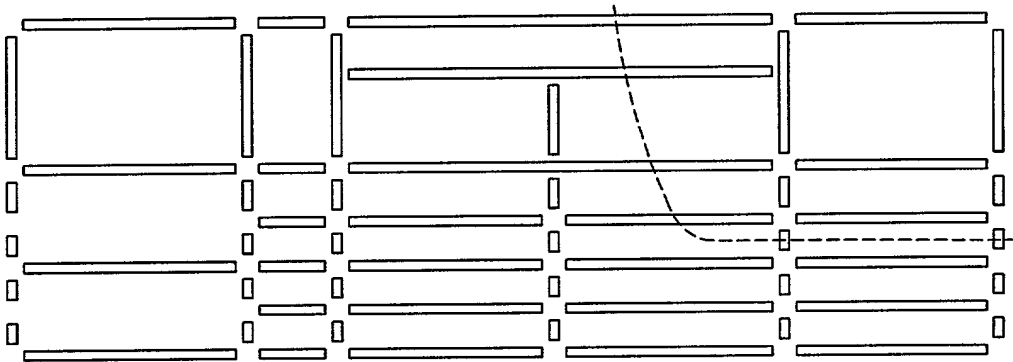


FIG. 13

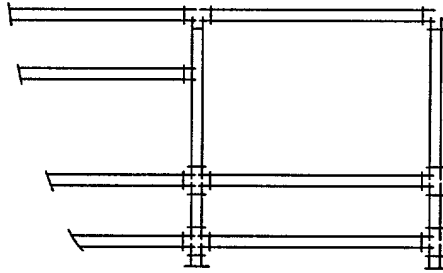


FIG. 14

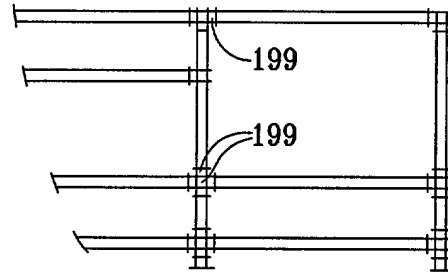


FIG. 15

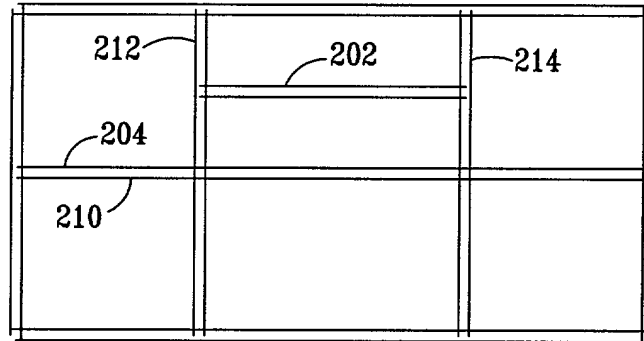


FIG. 16

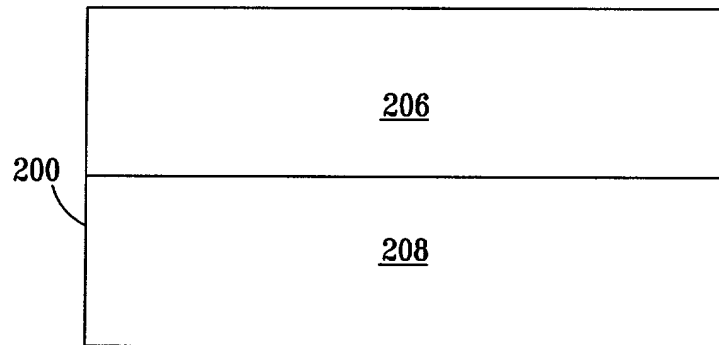


FIG. 17

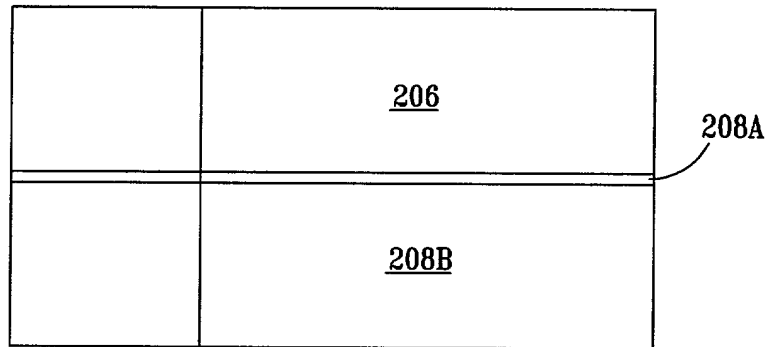


FIG. 18

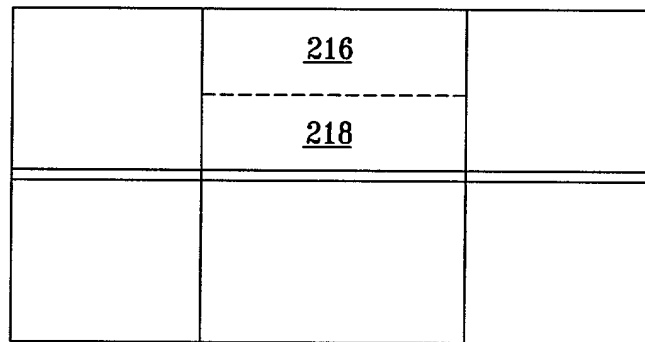


FIG. 19

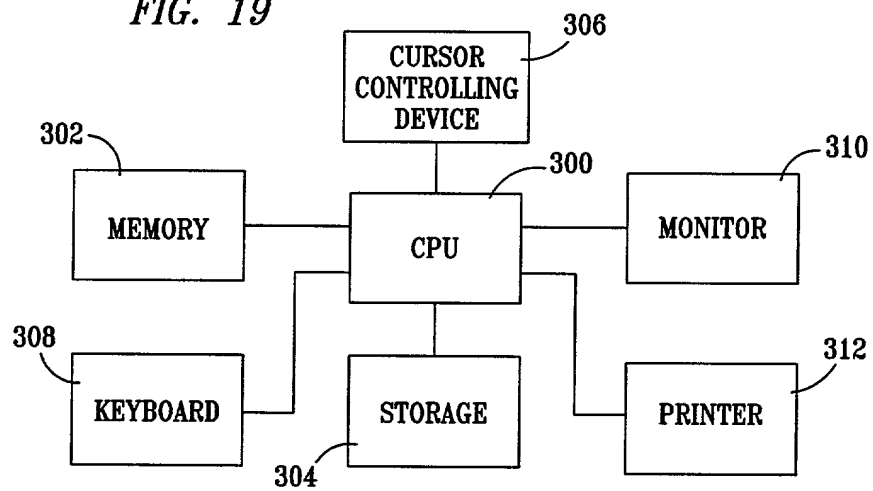


FIG. 20

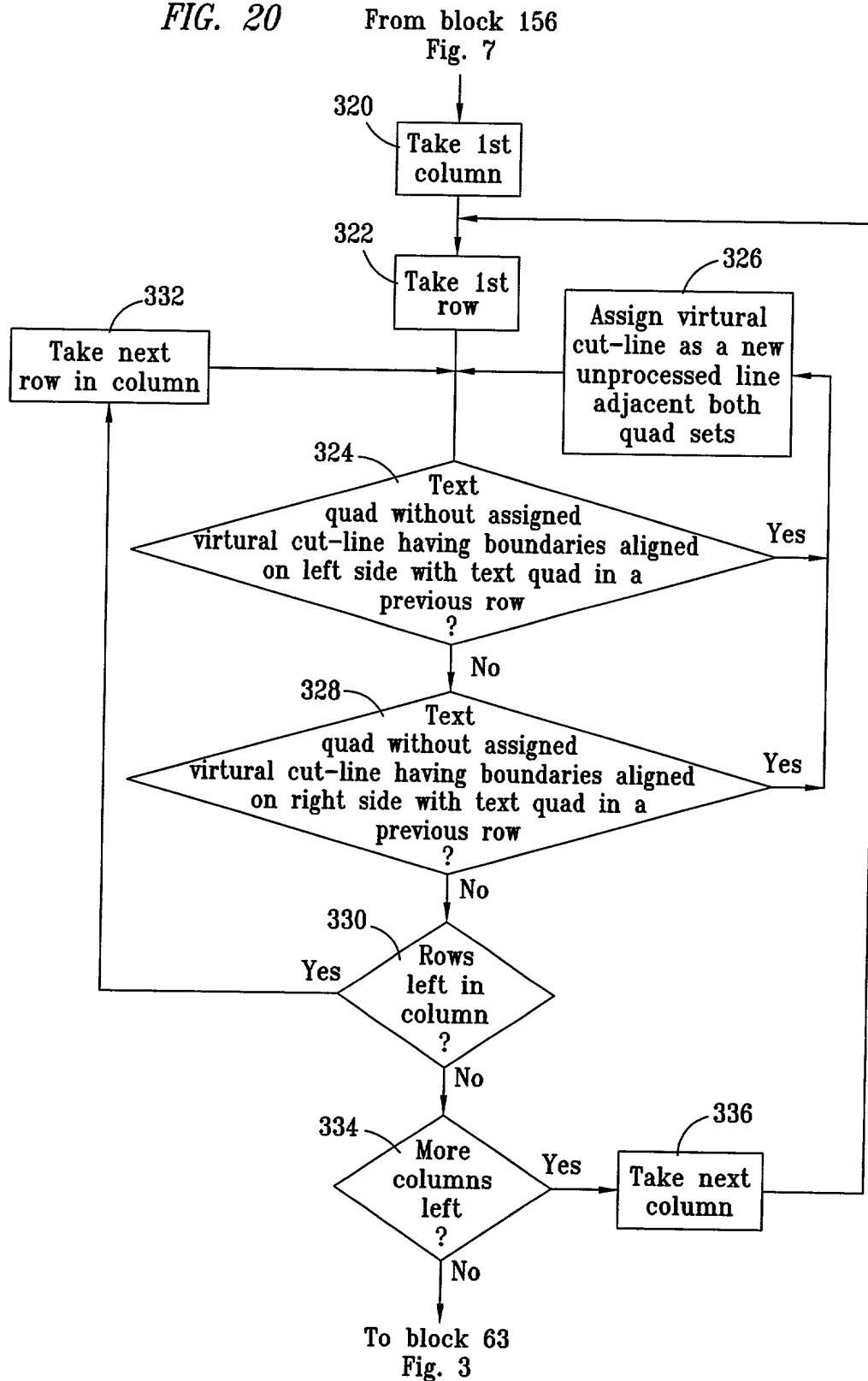


FIG. 21

350	PARAMETER	TEST CONDITIONS	LT1004Y-1.2			LT1004Y-2.5			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
V_Z	Reference voltage	$I_Z = 100 \mu A$	1.231	1.235	1.239	2.48	2.5	2.52	V
α_{V_Z}	Average temperature coefficient of reference voltage†	$I_Z = 10 \mu A$	352	20					ppm/°C
		$I_Z = 20 \mu A$			354		20		
$\Delta V_Z / \Delta t$	Long-term change in reference voltage	$I_Z = 100 \mu A$		20			20		ppm/khr
I_Z (min)	Minimum reference current			8			12		μA

356